

Technical Data Diode



maximum ratings

| | | |
|--|-------|------|
| Voltage, Reverse (VR) | 1200 | V |
| Voltage, Reverse Peak (VRM) | 1200 | V |
| Current at VR = 0V (IO) | A | |
| Current Average Rectified (IF) | 12 | A |
| Current, Surge Peak (IZM) | A | |
| Current, Surge (IFM) at tp = 10 ms | 200 | A |
| Max. Power Dissipation (PT) at TC = °C | W | |
| Max. Thermal Resistance (Rth J-C) | 2.0 | °C/W |
| Max. Junction Temperature (TJ) | + 175 | °C |

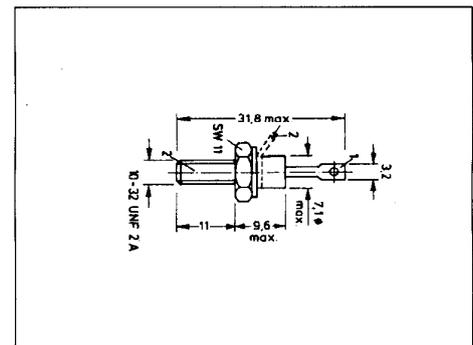
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|------|-----------------|
| NO. | MF 12 – 1200 |
| TYPE | Fast-Recovery |
| CASE | DO – 4 |
| | CATHODE TO CASE |

PERFORMANCE CHARACTERISTICS at TC = 25°C, unless otherwise noted

| NO. | SYMBOL | CONDITIONS | MIN. | MAX. | UNITS |
|-----|--------|-----------------------------|------|------|-------|
| 1. | VF | IF = 60 A (1) | - | 2.0 | V |
| 2. | IR | VR = 1200 V, TC = 125° C | - | 10 | mA |
| 3. | trr | IF = 1 A, di/dt = 25 A/μsec | - | 500 | ns |
| 4. | | | | | |
| 5. | | | | | |
| 6. | | | | | |
| 7. | | | | | |
| 8. | | | | | |
| 9. | | | | | |
| 10. | | | | | |
| 11. | | | | | |
| 12. | | | | | |
| 13. | | | | | |
| 14. | | | | | |
| 15. | | | | | |
| 16. | | | | | |
| 17. | | | | | |
| 18. | | | | | |

Notes (1) pulse-tested tp ≤ 300 μsec, duty cycle ≤ 2%
(2) typical value

DIMENSIONS
in mm



Marking MF 12-1200
Customer GENERAL PURPOSE